UVA Sensor: SUVAT05

Features SiC based material

Broad band UVA+UVB+UVC photodiode

Photovoltaic mode operation

TO-46 metal housing Good visible blindness

High responsivity and low dark current

Applications UV LED monitoring

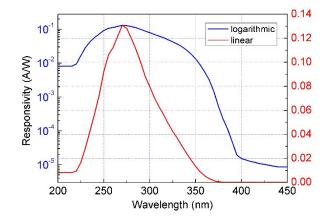
UV radiation dose measurement

UV Curing

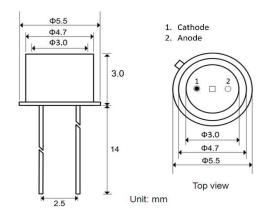


Parameter	Symbol	Value	Unit
Spectral characteristics (25 °C)			
Wavelength of peak responsivisity	λ_{max}	275	nm
Peak responsivisity (at 275 nm)	R _{max}	0.13	A/W
Spectral response range	-	200~380	nm
UV/visible rejection ratio (R _{max} /R _{400 nm})	VB	>104	-
General characteristics (25 °C)			
Chip size	А	0.25	mm ²
Dark current (1 V reverse bias)	I _d	<10	pA
Capacitance (at 0 V and 1 MHz)	С	25	pF
Temperature coefficient	T _c	-0.1	%/°C
Maximum ratings			
Operation temperature range	T _{opt}	-40~125	°C
Storage temperature range	T _{stor}	-40~125	°C
Soldering temperature (3 s)	T _{sold}	260	°C
Reverse voltage	V_{Rmax}	20	V

Spectral response



Package dimensions



^{*}Caution: ESD can damage the device hence please avoid ESD.